

Optical and electrical characteristics of FeS₂ thin films obtained in gas discharge

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Iron disulfide FeS₂ (pyrite) is a non-toxic material, and due to its wide distribution on Earth, it has the prospect of becoming a low-cost alternative for creating high-efficiency solar cells. This is facilitated both by its environmental friendliness and optical properties close to optimal for efficient conversion of radiation energy: the bandgap energy is 0.95 eV, and the optical absorption coefficient is more significant than 10^5 cm^{-1} at energy $h\nu > 1.4 \text{ eV}$. Iron and sulfur can form sulfides with different stoichiometric compositions and structures during film fabrication, which affects the material properties. Considering the complex zone structure, FeS₂ thin films with a wide range of intrinsic absorption (from 1 to 3.8 eV) are obtained. Depending on their optical properties, they can be used in solar cells as a photoactive absorbing layer or as a frontal translucent layer in heterostructures.

This paper presents the results of the study of electrical and optical properties of FeS₂ thin films obtained by sputtering in gas discharge plasma at temperatures from 250 to 350°C. To study electrical and optical properties, film samples were used on quartz glass substrates of 11 × 11 mm.



Fig 1. FeS₂ thin film samples on quartz glass substrates of 11 × 11 mm.

Transmission spectra of thin films were recorded using a spectrometer based on an MS 7504i spectral monochromator. A hydrogen source was used as an emission source.

The block diagram of the automated measuring system for studying the optical characteristics of ferroelectrics is shown in Figure 2 and dependence of FeS₂ film transmittance coefficient under hydrogen lamp illumination is shown in Figure 3



Fig2. The block diagram for studying the optical characteristics

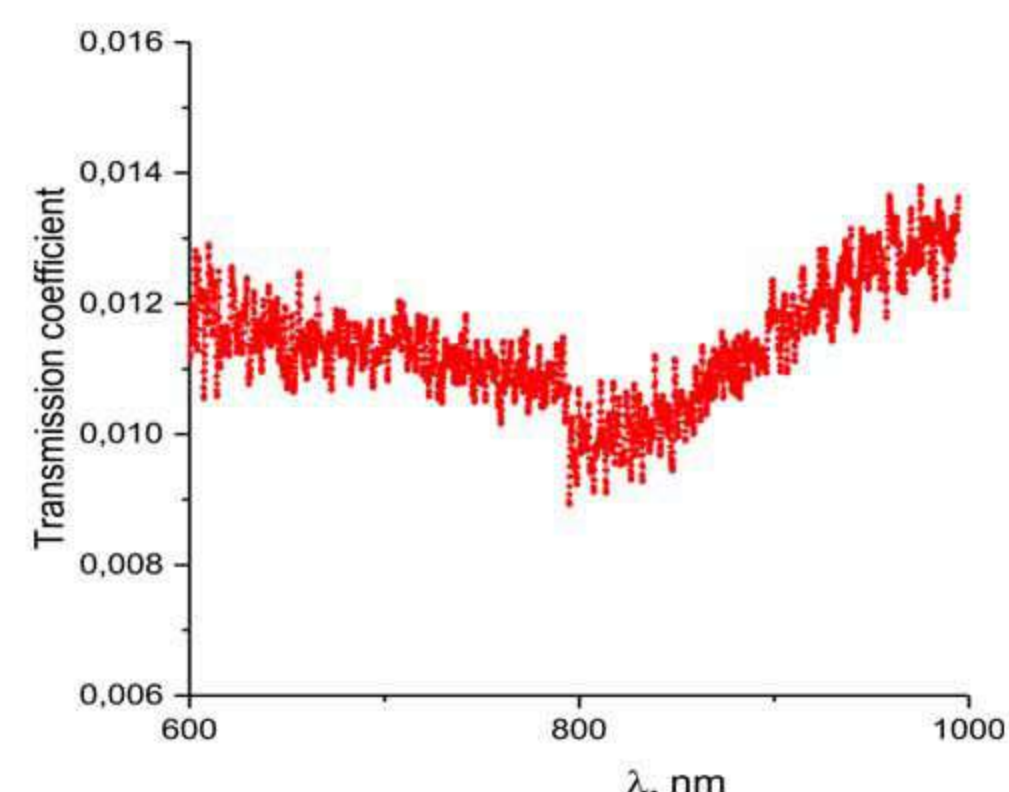


Fig3. FeS₂ film transmittance coefficient

The block diagram of the automated measuring system for studying the temperature dependence of dielectric spectra of ferroelectrics is shown in Figure 4 and temperature dependency of conductivity of the FeS₂ thin films is shown in Figure 5

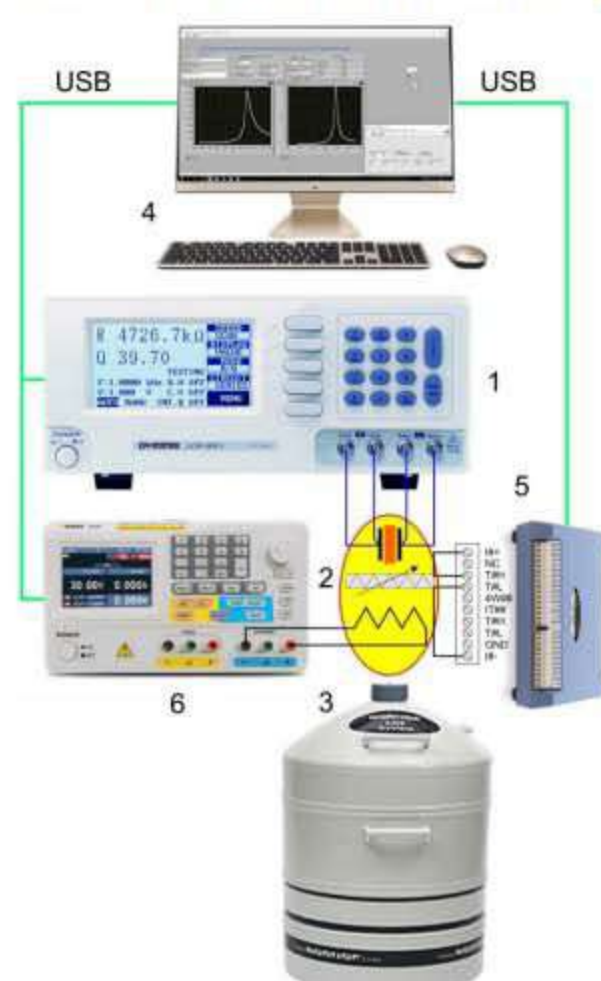


Fig4. The block diagram for studying the temperature dependence

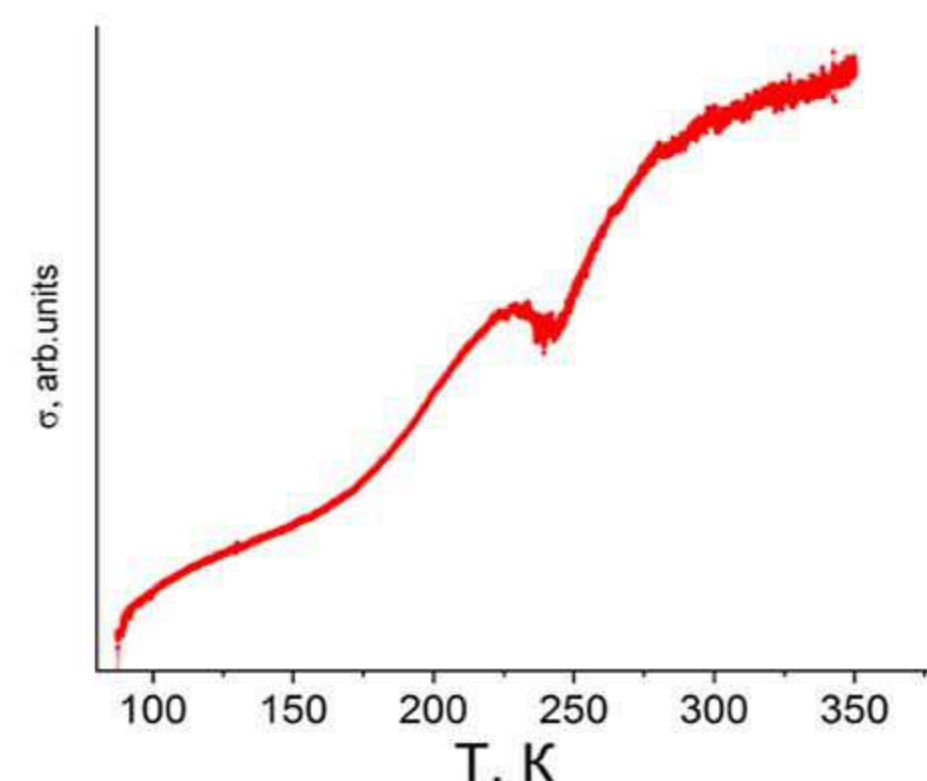


Fig5. The temperature dependency of conductivity of the FeS₂